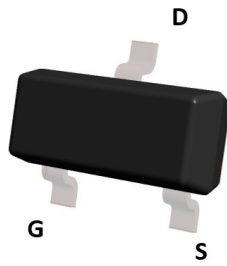
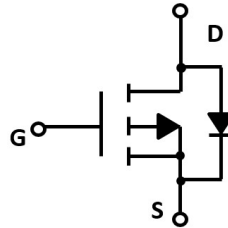
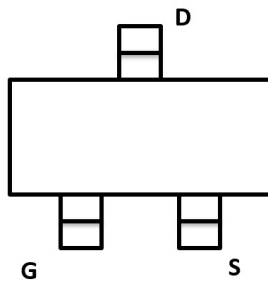


## P-Channel Enhancement Mode Field Effect Transistor



Top View

**SOT-23**



### Product Summary

- $V_{DS}$  -60 V
- $I_D$  -0.17 A
- $R_{DS(ON)}$ ( at  $V_{GS}=-10V$ ) < 8 ohm
- $R_{DS(ON)}$ ( at  $V_{GS}=-4.5V$ ) < 9.9 ohm

### General Description

- Trench Power LV MOSFET technology
- Low  $R_{DS(ON)}$
- Low Gate Charge

### Applications

- Video monitor
- Power management

### ■ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter   | Symbol          | Maximum                               | Unit                      |
|---|-----------------|---------------------------------------|---------------------------|
| Drain-source Voltage                                | $V_{DS}$        | -60                                   | V                         |
| Gate-source Voltage                                 | $V_{GS}$        | $\pm 20$                              | V                         |
| Drain Current                                       | $I_D$           | $T_A=25^\circ\text{C}$ @ Steady State | -0.17                     |
|   |                 | $T_A=70^\circ\text{C}$ @ Steady State | -0.14                     |
| Pulsed Drain Current <sup>A</sup>                   | $I_{DM}$        | 1.2                                   | A                         |
| Total Power Dissipation @ $T_A=25^\circ\text{C}$    | $P_D$           | 0.35                                  | W                         |
| Thermal Resistance Junction-to-Ambient <sup>B</sup> | $R_{\theta JA}$ | 357                                   | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range              | $T_J, T_{STG}$  | -55~+150                              | $^\circ\text{C}$          |

### ■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| BSS84         | F2           | B84.    | 3000                 | 30000                   | 120000                     | 7" reel       |



# BSS84

## ■ Electrical Characteristics ( $T_J=25^{\circ}\text{C}$ unless otherwise noted)

| Parameter                             | Symbol       | Conditions   | Min  | Typ  | Max       | Units    |
|---------------------------------------|--------------|--|------|------|-----------|----------|
| <b>Static Parameter</b>               |              |  |      |      |           |          |
| Drain-Source Breakdown Voltage        | $BV_{DSS}$   | $V_{GS}=0V, I_D=-250\mu A$                                 | -60  |      |           | V        |
| Zero Gate Voltage Drain Current       | $I_{DSS}$    | $V_{DS}=-60V, V_{GS}=0V$                                   |      |      | -1        | $\mu A$  |
| Gate-Body Leakage Current             | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$                                |      |      | $\pm 100$ | nA       |
| Gate Threshold Voltage                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$                             | -0.9 | -1.4 | -2.0      | V        |
| Static Drain-Source On-Resistance     | $R_{DS(on)}$ | $V_{GS}=-10V, I_D=-0.15A$                                  |      | 3.3  | 8         | $\Omega$ |
|                                       |              | $V_{GS}=-4.5V, I_D=-0.15A$                                 |      | 3.5  | 9.9       |          |
| Diode Forward Voltage                 | $V_{SD}$     | $I_S=-0.17A, V_{GS}=0V$                                    |      |      | -1.2      | V        |
| Maximum Body-Diode Continuous Current | $I_S$        |  |      |      | -0.17     | A        |
| <b>Dynamic Parameters</b>             |              |  |      |      |           |          |
| Input Capacitance                     | $C_{iss}$    | $V_{DS}=-30V, V_{GS}=0V, f=1\text{MHz}$                    |      | 43   |           | pF       |
| Output Capacitance                    | $C_{oss}$    |  |      | 2.9  |           |          |
| Reverse Transfer Capacitance          | $C_{rss}$    |  |      | 1.8  |           |          |
| <b>Switching Parameters</b>           |              |  |      |      |           |          |
| Total Gate Charge                     | $Q_g$        | $V_{GS}=-10V, V_{DS}=-30V, I_D=-0.15A$                     |      | 1.77 |           | nC       |
| Gate Source Charge                    | $Q_{gs}$     |  |      | 0.57 |           |          |
| Gate Drain Charge                     | $Q_{gd}$     |  |      | 0.18 |           |          |
| Reverse Recovery Charge               | $Q_{rr}$     | $I_F=-0.15A, di/dt=100A/\mu s$                             |      | 13   |           |          |
| Reverse Recovery Time                 | $t_{rr}$     |  |      | 23   |           |          |
| Turn-on Delay Time                    | $t_{D(on)}$  | $V_{GS}=-4.5V, V_{DD}=-30V, I_D=-0.15A, R_{GEN}=2.5\Omega$ |      | 8.6  |           | ns       |
| Turn-on Rise Time                     | $t_r$        |  |      | 20   |           |          |
| Turn-off Delay Time                   | $t_{D(off)}$ |  |      | 15   |           |          |
| Turn-off Fall Time                    | $t_f$        |  |      | 77   |           |          |

A. Pulse Test: Pulse Width  $\leq 10\mu s$ , Duty cycle  $\leq 2\%$ .

B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.



■ Typical Performance Characteristics

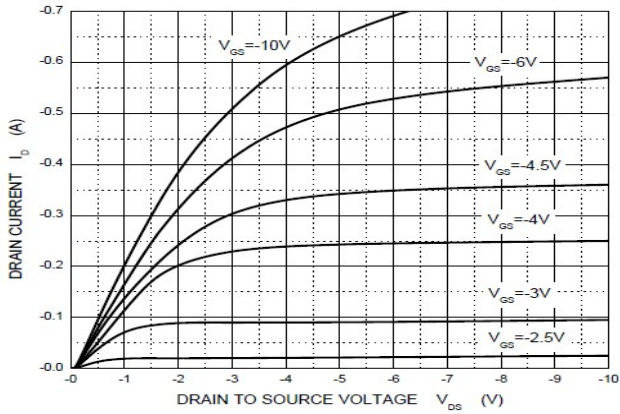


Figure1. Output Characteristics

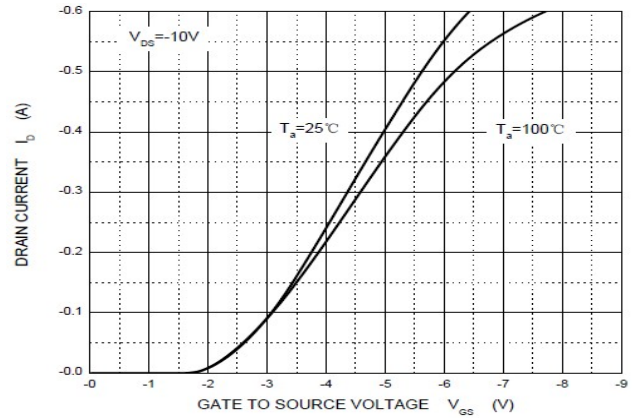


Figure2. Transfer Characteristics

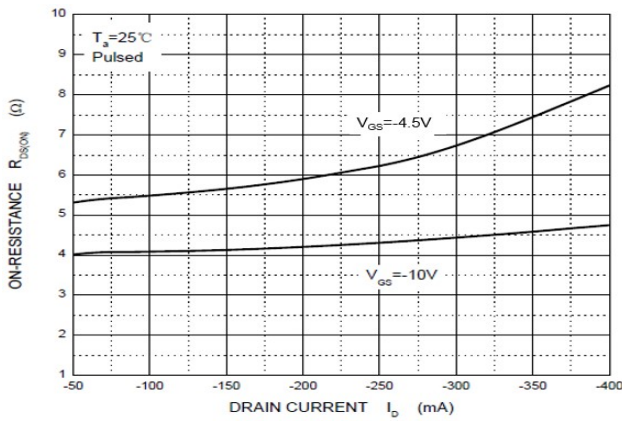


Figure3. Drain-Source on Resistance

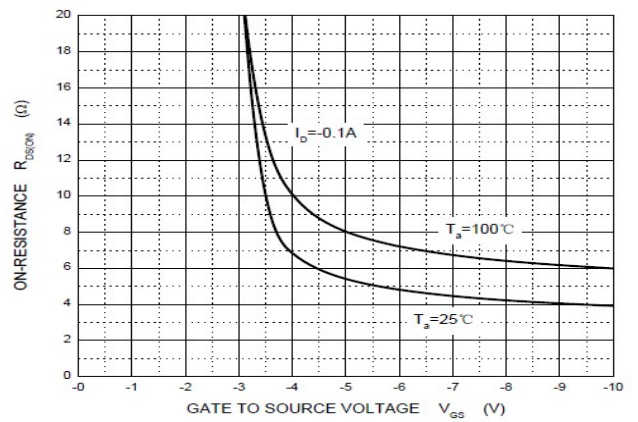


Figure4. Drain-Source on Resistance

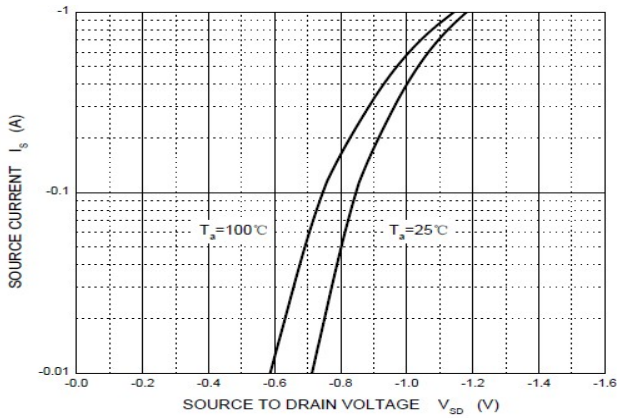


Figure5. Diode Forward Voltage vs. current

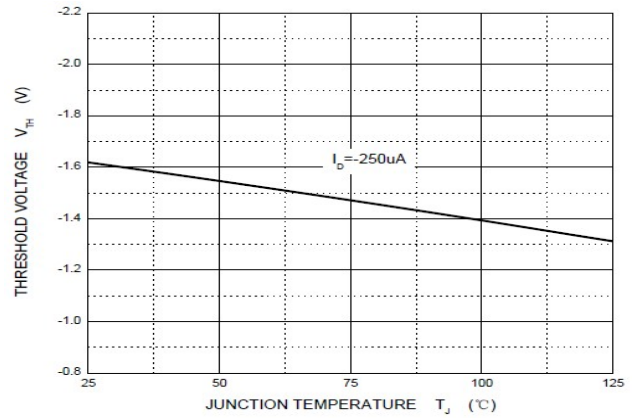
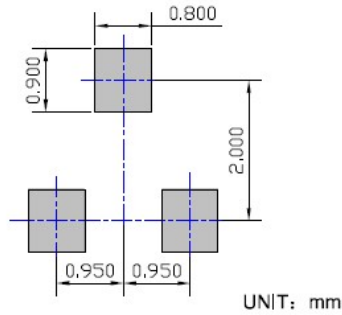
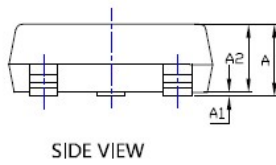
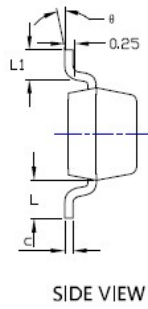
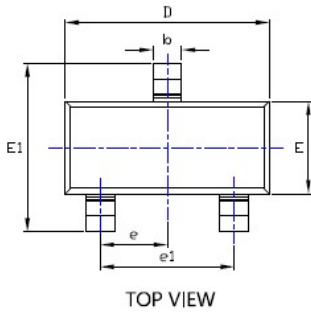


Figure6. Gate Threshold vs. Junction Temperature

## ■ SOT-23 Package information



SUGGESTED SOLDER PAD LAYOUT

| SYMBOL | DIMENSIONS |       |       |            |       |       |
|--------|------------|-------|-------|------------|-------|-------|
|        | INCHES     |       |       | MILLimeter |       |       |
|        | MIN.       | NOM.  | MAX.  | MIN.       | NOM.  | MAX.  |
| A      | 0.035      | ---   | 0.045 | 0.900      | ---   | 1.150 |
| A1     | 0.000      | ---   | 0.004 | 0.000      | ---   | 0.100 |
| A2     | 0.035      | 0.038 | 0.041 | 0.900      | 0.975 | 1.050 |
| b      | 0.012      | 0.016 | 0.020 | 0.300      | 0.400 | 0.500 |
| c      | 0.004      | ---   | 0.008 | 0.100      | ---   | 0.200 |
| D      | 0.110      | 0.114 | 0.118 | 2.800      | 2.900 | 3.000 |
| E      | 0.047      | 0.051 | 0.055 | 1.200      | 1.300 | 1.400 |
| E1     | 0.089      | 0.094 | 0.100 | 2.250      | 2.400 | 2.550 |
| e      | 0.037 TYP  |       |       | 0.950 TYP  |       |       |
| e1     | 0.071      | 0.075 | 0.079 | 1.800      | 1.900 | 2.000 |
| L      | 0.022 REF  |       |       | 0.550 REF  |       |       |
| L1     | 0.012      | 0.016 | 0.200 | 0.300      | 0.400 | 0.500 |
| e      | 0*         | ---   | 8*    | 0*         | ---   | 8*    |

NOTE:

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



## BSS84

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